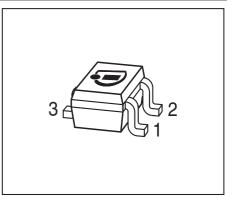


BFR193W

Low Noise Silicon Bipolar RF Transistor

- For low noise, high-gain amplifiers up to 2 GHz
- For linear broadband amplifiers
- $f_{\rm T}$ = 8 GHz, $NF_{\rm min}$ = 1 dB at 900 MHz
- Pb-free (RoHS compliant) package
- Qualification report according to AEC-Q101 available





ESD (Electrostatic discharge) sensitive device, observe handling precaution!

| Туре | Marking | | Pin | Config | Package | | |
|---------------------------------------|--------------------|----------|-------------------|---------|---------|-----|------|
| BFR193W | RCs | 1 = B | 2 = E | | 3 = C | SOT | 323 |
| Maximum Ratings at $T_A = 25$ | °C, unless | otherwis | se sp | ecified | | | |
| Parameter | | | Syr | nbol | Value | | Unit |
| Collector-emitter voltage | | | VCE | EO | 12 | | V |
| Collector-emitter voltage | | | | ES | 20 | | |
| Collector-base voltage | | | VCE | 30 | 20 | | |
| Emitter-base voltage | | | VEE | 30 | 2 | | |
| Collector current | | | I _C | | 80 | m | |
| Base current | | | I _B | | 10 | | |
| Total power dissipation ¹⁾ | | | Ptot | t | 580 | | mW |
| <i>T</i> _S ≤ 63°C | | | | | | | |
| Junction temperature | nction temperature | | T _J 15 | | 150 | °C | |
| Storage temperature | | | T _{Ste} | a | -55 15 | 50 | 7 |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|-------------------|-------|------|
| Junction - soldering point ²⁾ | R _{thJS} | 150 | K/W |

 $^{1}T_{S}$ is measured on the collector lead at the soldering point to the pcb

²For calculation of R_{thJS} please refer to Application Note AN077 (Thermal Resistance Calculation)



| Parameter | Symbol | Values | | | Unit |
|---|----------------------|--------|------|------|------|
| | | min. | typ. | max. |] |
| DC Characteristics | | | | • | |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | 12 | - | - | V |
| <i>I</i> _C = 1 mA, <i>I</i> _B = 0 | | | | | |
| Collector-emitter cutoff current | I _{CES} | - | - | 100 | μA |
| $V_{\rm CE}$ = 20 V, $V_{\rm BE}$ = 0 | | | | | |
| Collector-base cutoff current | I _{CBO} | - | - | 100 | nA |
| $V_{\rm CB}$ = 10 V, $I_{\rm E}$ = 0 | | | | | |
| Emitter-base cutoff current | I _{EBO} | - | - | 1 | μA |
| <i>V</i> _{EB} = 1 V, <i>I</i> _C = 0 | | | | | |
| DC current gain | h _{FE} | 70 | 100 | 140 | - |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, pulse measured | | | | | |

Electrical Characteristics at T_A = 25 °C, unless otherwise specified



| Parameter | Symbol | Values | | 1 | Unit | |
|--|---------------------------------|--------|------|------|------|--|
| | | min. | typ. | max. | | |
| AC Characteristics (verified by random sampling) | | | | | | |
| Transition frequency | f _T | 6 | 8 | - | GHz | |
| <i>I</i> _C = 50 mA, <i>V</i> _{CE} = 8 V, <i>f</i> = 500 MHz | | | | | | |
| Collector-base capacitance | C _{cb} | - | 0.74 | 1 | pF | |
| $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$, | | | | | | |
| emitter grounded | | | | | | |
| Collector emitter capacitance | C _{ce} | - | 0.28 | - | | |
| $V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$, | | | | | | |
| base grounded | | | | | | |
| Emitter-base capacitance | C _{eb} | - | 1.8 | - | | |
| V _{EB} = 0.5 V, <i>f</i> = 1 MHz, V _{CB} = 0 , | | | | | | |
| collector grounded | | | | | | |
| Minimum noise figure | NF _{min} | | | | dB | |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | | |
| <i>f</i> = 900 MHz | | - | 1 | - | | |
| <i>f</i> = 1.8 GHz | | - | 1.6 | - | | |
| Power gain, maximum available ¹⁾ | G _{ma} | | | | | |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt,}$ $Z_{\rm L}$ = $Z_{\rm Lopt,}$ | | | | | | |
| <i>f</i> = 900 MHz | | - | 16 | - | | |
| <i>f</i> = 1.8 GHz | | - | 10.5 | - | | |
| Transducer gain | S _{21e} ² | | | | dB | |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω , | | | | | | |
| <i>f</i> = 900 MHz | | - | 13.5 | - | | |
| <i>f</i> = 1.8 GHz | | - | 8 | - | | |
| Third order intercept point at output ²⁾ | IP ₃ | - | 30 | - | dBm | |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω , | | | | | | |
| <i>f</i> = 900 MHz | | | | | | |
| 1dB Compression point | P _{-1dB} | - | 13 | - |] | |
| $I_{\rm C}$ = 30 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω, | | | | | | |
| <i>f</i> = 900 MHz | | | | | | |

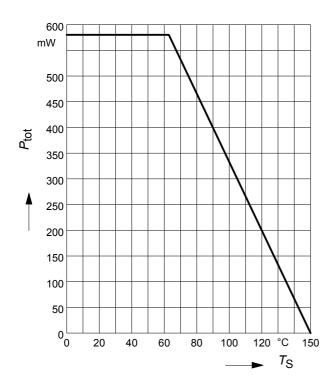
Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

 ${}^{1}G_{\text{ma}} = |S_{21} / S_{12}| (k - (k^{2} - 1)^{1/2})$

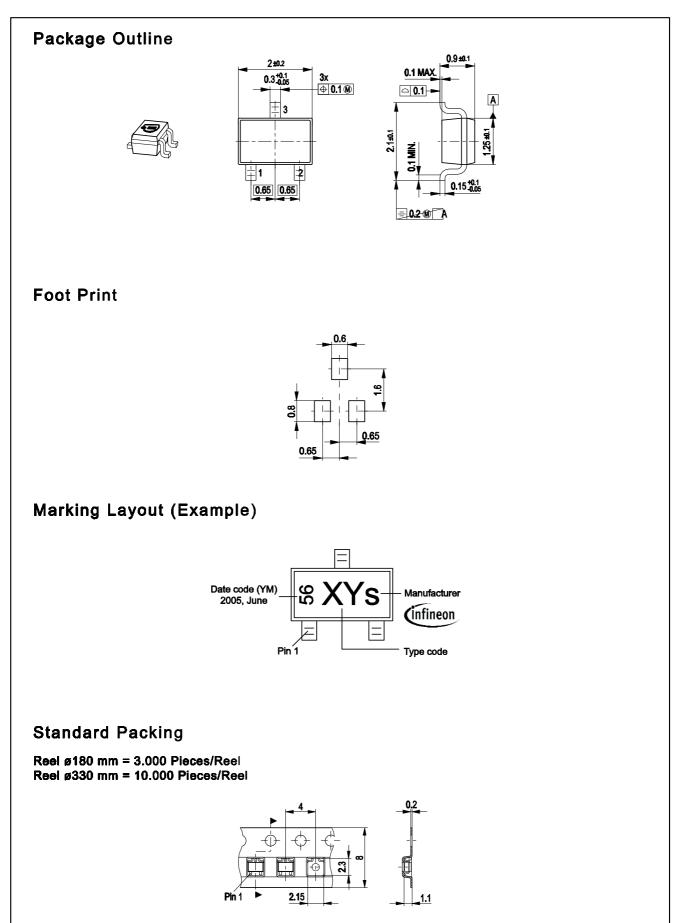
 2 IP3 value depends on termination of all intermodulation frequency components. Termination used for this measurement is 50 Ω from 0.2 MHz to 12 GHz



Total power dissipation $P_{tot} = f(T_S)$









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